

High Speed Switching Diode



SOT-323

Features

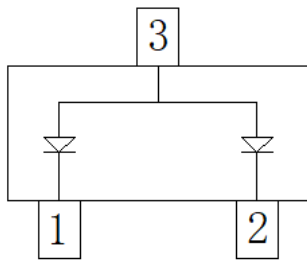
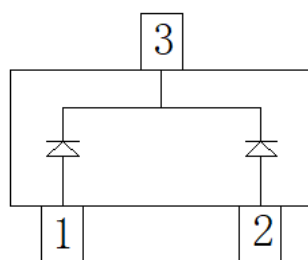
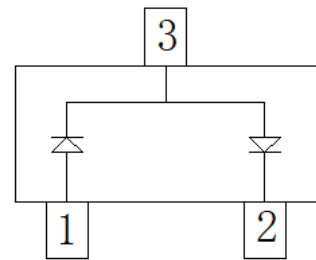
- Epoxy meets UL-94 V-0 flammability rating and halogen free
- Moisture Sensitivity Level 1
- V_{BR} 100V
- I_{FAV} 150mA@ Single diode loaded
- Part no. with suffix "Q" means AEC-Q101 qualified

Applications

- Extreme fast switches
- Automotive

Mechanical Data

- **Case:** SOT-323
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102

BAW56WTQ
Marking:KJCBAV70WTQ
Marking:KJABAV99WTQ
Marking: KJG■ Maximum Ratings ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	CONDITIONS	VALUE
Reverse Breakdown Voltage	V_{BR}	V		100
Average Forward Current	$I_{FAV[1]}$	mA		150
Non-Repetitive Peak Forward Surge Current	I_{FSM}	A	$t_p=1\text{ ms}$	1
Power Dissipation	$P_{tot}^{(1)(2)}$	mW		200
Thermal Resistance Junction to Ambient	$R_{thJA}^{(2)}$	$^{\circ}\text{C/W}$		625
Maximum Junction Temperature	T_j	$^{\circ}\text{C}$		-55 to +150
Storage Temperature Range	T_{stg}	$^{\circ}\text{C}$		-55 to +150

(1) Single diode loaded

(2) Device mounted on an FR4 PCB(1.0 x 1.0 x 0.06 inch), single-sided copper, tin-plated and standard footprint.

BAW56WTQ&BAV70WTQ&BAV99WTQ

■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	CONDITIONS	MIN	MAX
Forward Voltage	V _F	V	I _F =1mA		0.715
			I _F =10mA		0.855
			I _F =50mA		1.0
			I _F =150mA		1.25
Reverse Current	I _R	μA	V _R =75V		1
Reverse Breakdown Voltage	V _{BR}	V	I _R =100μA	100	
Diode Capacitance	C _j	pF	V _R =V _F =0V, f =1MHz		2
Reverse Recovery Time	t _{rr}	ns	I _F =10mA, I _{rr} =0.1I _R , R _L =100Ω		4

■ Ordering Information (Example)

PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
BAW56WTQ BAV70WTQ BAV99WTQ	F2	Approximate 0.006	3000	30000	120000	7" reel

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■ Characteristics (Typical)

Fig.1: P_D - T_A

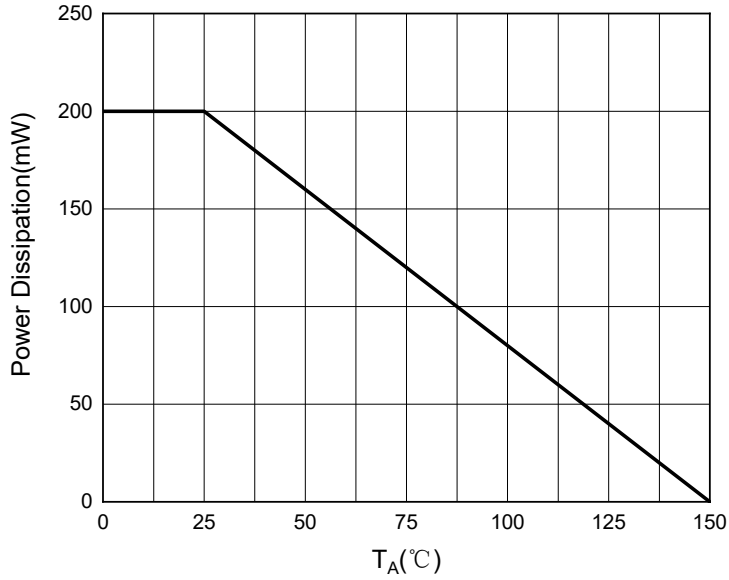


Fig.2: Capacitance Characteristics

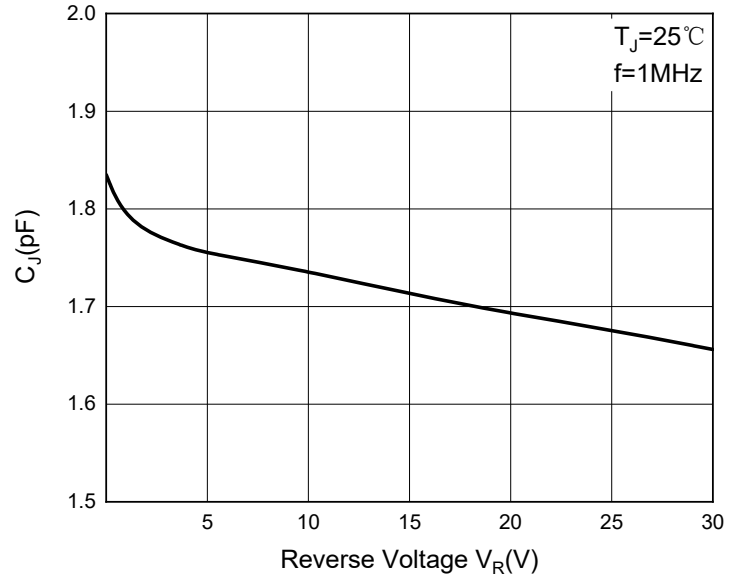


Fig.3: Forward Characteristics

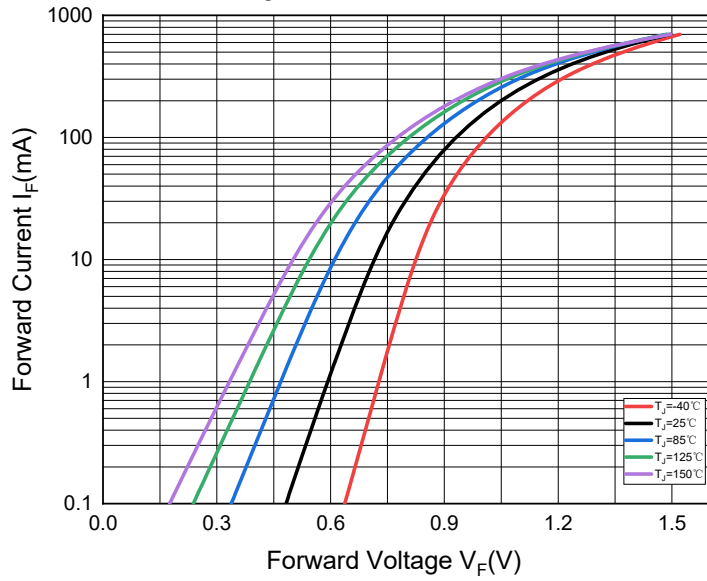
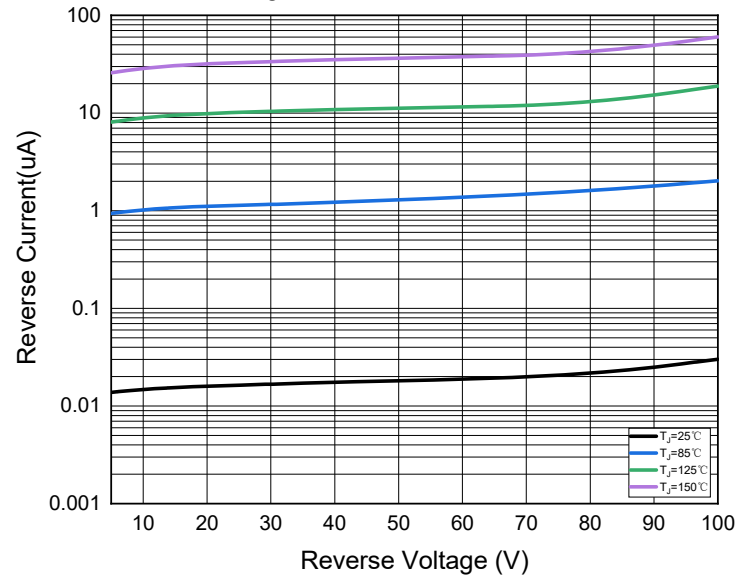
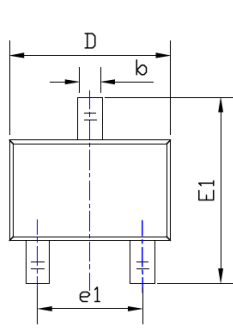


Fig.4: Reverse Characteristics

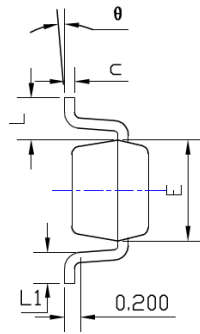


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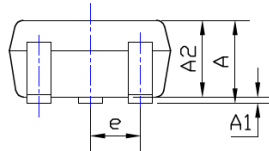
■ Outline Dimensions



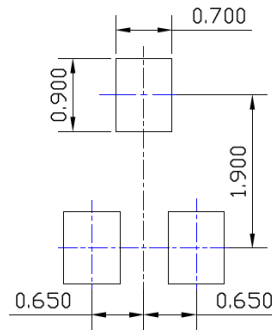
TOP VIEW



SIDE VIEW



SIDE VIEW



UNIT: mm

SUGGESTED SOLDER PAD LAYOUT

SYMBOL	DIMENSIONS			
	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.035	0.043	0.900	1.100
A1	0.000	0.004	0.000	0.100
A2	0.035	0.039	0.900	1.000
b	0.006	0.016	0.150	0.400
c	0.004	0.010	0.100	0.250
D	0.071	0.087	1.800	2.200
E	0.045	0.053	1.150	1.350
E1	0.085	0.096	2.150	2.450
e	0.026TYP		0.650TYP	
e1	0.047	0.055	1.200	1.400
L	0.021REF		0.525REF	
L1	0.010	0.018	0.260	0.460
θ	0°	8°	0°	8°

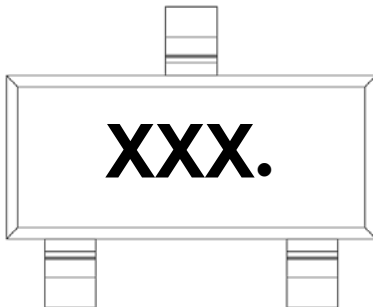
NOTE:

1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.

2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.

3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

■ Marking Information



PN	Marking Code
BAW56WTQ	KJC
BAV70WTQ	KJA
BAV99WTQ	KJG

Note:

1. All marking is at middle of the product body
2. All marking is in laser marking
3. XXX is Marking Code
4. Body color: Black

BAW56WTQ&BAV70WTQ&BAV99WTQ

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